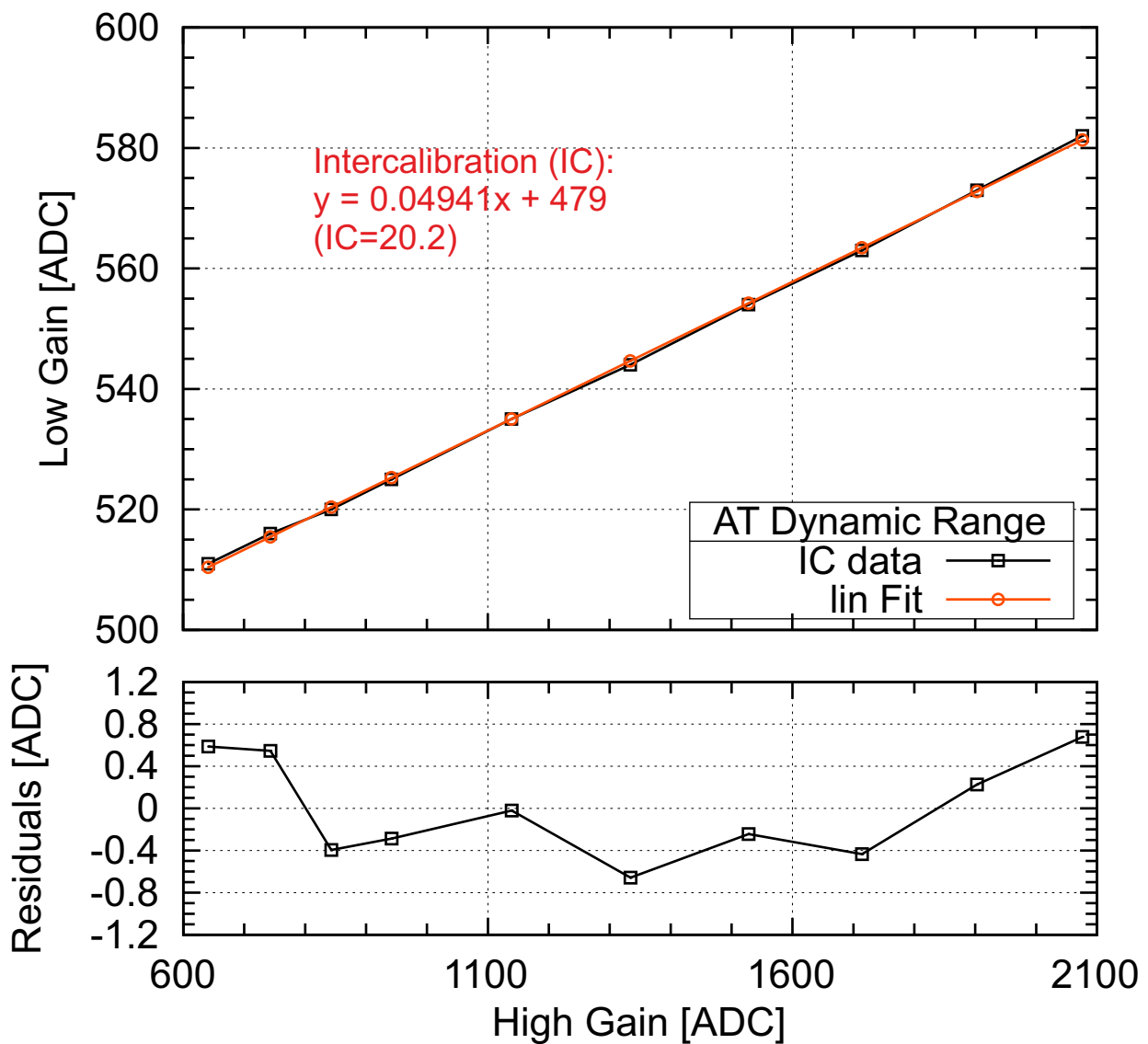


SP2E on HBU5 in Testbeam Setting



HG=600fF, LG=1200fF, H=110010, AT-thres=260, AGain_thres=350,
Charge Injection (new generator) via 20dB and 100pF)
Power Pulsing (switch-on time 212 μ s).
1MIP=1.7pC (gain=7E5, light yield=15px/MIP)
Plot is for memory cell 4 (counting 0 to 15).